

3A, 1.25MHZ HIGH PERFORMANCE SYNCHRONOUS BUCK CONVERTER

Description

The AP3436/A is a step-down DC-DC converter with integrated power stage capable of driving up to 3A continuous output current. It integrates 2 N-channel power MOSFETs with low on-resistance. Current mode control provides fast transient response and cycle-by-cycle current limit.

For AP3436, the regulator adopts current-mode in forced pulse-width modulation (PWM) mode with 1.25MHz switching frequency internally, which allows small-sized components, such as capacitors and inductors. This feature greatly simplifies the design of switch-mode power supplies. Under PWM mode, the device remains at the fixed PWM operation (typical at 1.25MHz), regardless of if the load current is high or low.

For AP3436A, the regulator operates in either fixed PWM mode or a pulse-skipping modulation (PSM) mode depending on the different load conditions. The device can operate at typical 1.25MHz fixed switching frequency under heavy load condition. At light load, the regulator enters a PSM mode to minimize the switching loss by reducing the switching frequency.

The AP3436/A provides EN function. Pulling this pin high statically enables the device while pulling the pin low statically for longer than 10µs will shut it down.

Under Voltage Lockout is internally set at 2.75V for V_{CC} detection. The output voltage startup ramp is controlled by the soft start. An open drain power good signal indicates the output is within 75% to 125% of its nominal voltage.

The AP3436/A is available in U-DFN3030-10 package.

Applications

- Desktop & Notebook
- Low Voltage, High Density Power System
- Consumer Application Such as Set Top Box, LCD Display and CPE Equipment

Pin Assignments

(Top View) Pin 1 Mark FB 1 10 EN VCC 2 11 9 PGOOD VIN 3 EP 8 BOOT GND 4 1 7 SW GND 5 1 6 SW

U-DFN3030-10

Features

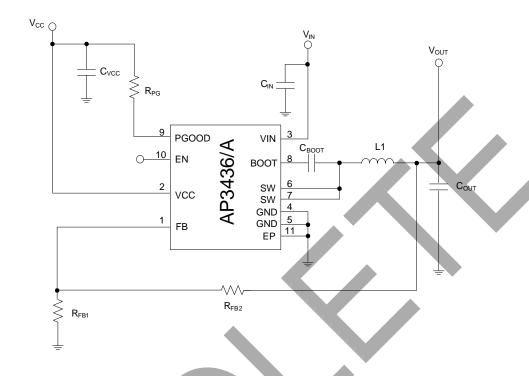
- Analog Power Input Vcc Range: 3.0V to 5.5V
- Power Input V_{IN} Range: 1.3V to 5.5V
- 0.6V Reference Voltage with ±1.5% Precision
- 2 MOSFETs (Typ 50mΩ) for High Efficiency at 3A Loads
- High Efficiency: Up to 95%
- Output Current: 3A
- Current Mode Control
- Built-in Soft Start Function
- UV and OV Power Good Output
- Built-in UV and OV Protection Function
- Built-in Over Current Protection
- Built-in Thermal Shutdown Function
- Thermally Enhanced 3mm×3mm DFN Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit



Note 4: When using a single power supply for V_{CC} and V_{IN}, a 4.7Ω resistor should be placed between them for noise isolation.

				I	
Component Value		Unit	Component	Value	Unit
		μF	Cin	44	μF
R _{PG}	10	kΩ	Своот	0.1	μF
R _{FB2}	TBD	kΩ	L1	1.5	μΗ
R _{FB1}	TBD	kΩ	Соит	88	μF

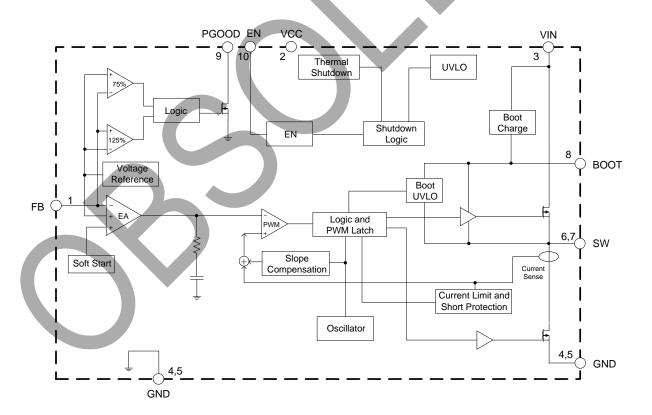
Table 1. Component Guide



Pin Descriptions

Pin Number	Pin Name	Function
1	FB	Voltage Feedback Input. Connect to Vou⊤ through a voltage divider to set the output voltage
2	VCC	Analog Power Input
3	VIN	Power Input
4, 5	GND	Ground. Must be Connected to GND on PCB
6, 7	SW	Power Switch Output
8	BOOT	High Side Switch Driver Supply
9	PGOOD	Open Drain Power Good Output
10	EN	Enable
11	Exposed Pad	Thermal Connection to the PCB. Must be connected to GND on PCB

Functional Block Diagram





Absolute Maximum Ratings (Note 5)

Symbol	Parameter	Rating	Unit
V _{CC} , V _{IN}	VCC, VIN Pin Voltage	-0.3 to 6	V
VEN	EN Pin Voltage	-0.3 to 6	V
Vsw	SW Pin Voltage	-0.3 to V _{IN} +0.3	V
Vsw_transient	SW Pin Transient Voltage (<50ns)	-5 to V _{IN} +5	V
V _{FB}	FB Pin Voltage	-0.3 to 6	V
V _{PGD}	PGOOD Pin Voltage	-0.3 to 6	V
VBOOT_SW	BOOT to SW Voltage	0 to 6	V
θја	Thermal Resistance (Junction to Ambient, Simulation)	33	°C/W
θυς	Thermal Resistance (Junction to Case)	3	°C/W
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
TLEAD	Lead Temperature (Soldering, 10sec)	+260	°C
Vнвм	ESD (Human Body Model)	2000	V
Vмм	ESD (Machine Model)	200	V

Note 5: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Мах	Unit
Vcc	Analog Input Voltage	3.0	5.5	V
V _{IN}	V _{IN} Power Input Voltage			V
IOUT(MAX)	3	-	Α	
Vouт	Output Voltage	0.8	Vin	V
TA	Operating Ambient Temperature	-40	+85	°C



Electrical Characteristics (V_{CC} = 5V, V_{IN} = 5V, T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
SUPPLY VOLTAGE (VCC,	VIN PIN)				•	
Vcc	Analog Power Input Voltage	_	3.0	-	5.5	V
V _{IN}	Power Input Voltage	_	1.3	-	5.5	V
lα	Quiescent Current	V _{FB} = 1.5V, V _{CC} = 5V, V _{IN} = 5V	-	400	_	μA
ISHDN Shutdown Supply Current		$V_{EN} = 0V,$ $3.0V \le V_{CC} \le 5.5V,$ $1.3V \le V_{IN} \le 5.5V$		-	1	μΑ
POWER ON RESET						
Vuvlo	Internal Under Voltage Lockout Threshold for V _{CC}	-	-	2.75	2.85	V
V _{HYS} _vcc	Internal Under Voltage Hysteresis for Vcc	-	-	150	_	mV
VOLTAGE REFERENCE (FB PIN)						
VfB	Voltage Reference	3.0V ≤ V _{CC} ≤ 5.5V	0.591	0.600	0.609	V
INTERNAL PWM FREQUE	NCY					
f	PWM Frequency	3.0V ≤ V _{CC} ≤ 5.5V	1.0	1.25	1.5	MHz
MOSFET SPEC						
	High Oids Outstand	VBOOT_SW = 5.0V	-	50	100	mΩ
R _{ON_} H	High Side Switch On-resistance	VBOOT_SW = 3.0V	_	70	140	mΩ
David	Low Side Switch On-resistance	Vcc = 5.0V	_	50	100	mΩ
Ron_L	Low Side Switch On-resistance	V _{CC} = 3.0V	_	70	140	mΩ
CURRENT LIMIT						
Ішміт	Current Limit Threshold	_	4.8	7.6	_	Α
THERMAL SHUTDOWN						
T _{TSD}	Thermal Shutdown	_	_	+160	_	°C
-	Hysteresis	-	-	+20	_	°C
BOOT SPEC (BOOT PIN)						
Rвоот	BOOT Charge Resistor	Vcc = 5.0V	-	16	_	Ω
_	BOOT to SW UVLO	Vcc = 3.0V	-	2.2	-	V
SOFT START						
tss	Soft Start Time	-	0.8	_	2	ms



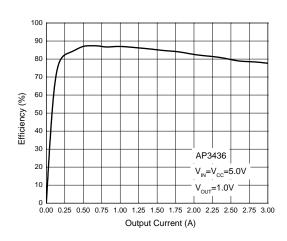
Electrical Characteristics (Cont. V_{CC} = 5V, V_{IN} = 5V, T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
ENABLE (EN PIN)							
Ven_L		-	_	_	0.8	V	
V _{EN_} H	EN Pin Threshold	-	1.6	-	-	V	
POWER GOOD (PGOO	D PIN)						
		V _{FB} falling (Fault)	70	75	_	%V _{REF}	
.,		V _{FB} rising (Good)	77	82	-		
V _{FBTH}	Feedback Threshold	V _{FB} rising (Fault)	_	125	130		
		V _{FB} falling (Good)		118	123		
tpg_dly	Delay Time for PGOOD from High to Low	-	-	30	_	μs	
Rpg	Internal Power Good Pull Low Resistance	-	_	_	150	Ω	
R _{PG_UP}	External Pull-up Resistance Range	-	3000	_	_	Ω	
SYSTEM PERFORMAN	ICE						
V _{UVP}	Output Under Voltage Protection Threshold	V _{IN} = 1.3 to 5.5V	-	_	0.5× V _{OUT}	V	
tuvp	Delay Time for UVP Triggered	V _{IN} = 1.5 to 5V	_	65	_	μs	
Vovp	Output Over Voltage Protection Threshold	V _{IN} = 1.3 to 5.5V	1.5 х Vоит	_	_	V	
tovp	Delay Time for OVP Triggered	V _{IN} = 1.5 to 5V	_	65	_	μs	
Іоит	Output Current	V _{IN} = 1.5 to 5V, V _{OUT} = 1.0V	3	_	_	А	
-	Output Voltage Line Regulation	V _{IN} = 1.5 to 5V, I _{OUT} = 100mA	_	0.4	_	%x Vout/V	
-	Output Voltage Load Regulation	Iout = 0A to 3A	_	0.3	_	%x Vout/A	
VTRAN	Output Voltage Load Transient	V _{IN} = 5V, V _{OUT} = 1.0V, dI/dt = 400mA/μs	_	±2.5	_	%× Vout/A	
η	Efficiency	Vcc = 5V, V _{IN} =5V, Iout = 3A, Vout = 1.2V	_	80	_	%	

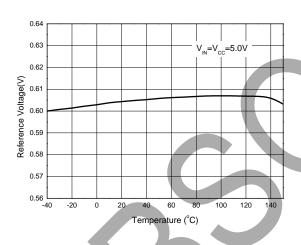


Performance Characteristics

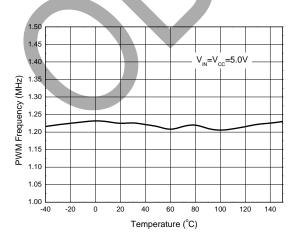
Efficiency vs. Output Current



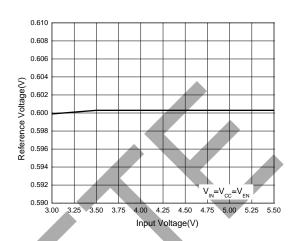
Reference Voltage vs. Temperature



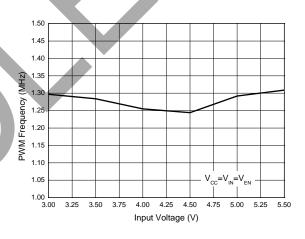
PWM Frequency vs. Temperature



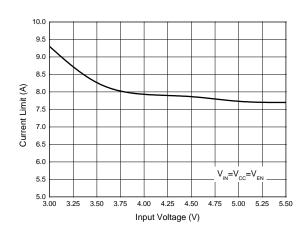
Reference Voltage vs. Input Voltage



PWM Frequency vs. Input Voltage



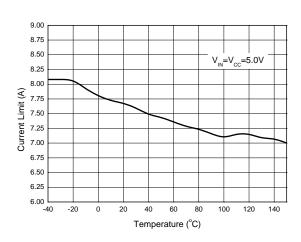
Current Limit vs. Input Voltage



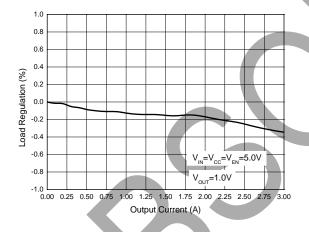


Performance Characteristics (Cont.)

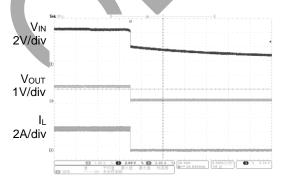
Current Limit vs. Temperature



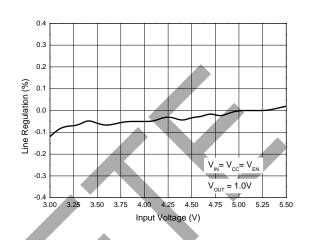
Load Regulation vs. Output Current



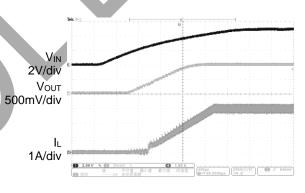
Power off Waveform (V_{IN}=V_{CC}=5V, V_{OUT}=1V, I_{OUT}=3A)



Line Regulation vs. Input Voltage

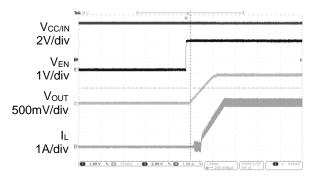


Power on Waveform (V_{IN}=V_{CC}=5V, V_{OUT}=1V, I_{OUT}=3A)



Time 400µs/div

Enable Waveform (V_{IN}=V_{CC}=5V, V_{OUT}=1V, I_{OUT}=3A)

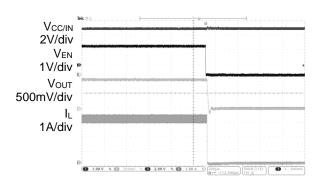


Time 1ms/div



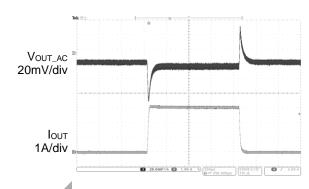
Performance Characteristics (Cont.)

Disable Waveform (V_{IN}=V_{CC}=5V, V_{OUT}=1V, I_{OUT}=3A)



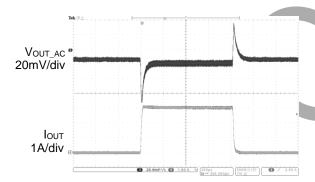
Time 200µs/div

Load Transient Response (VIN=VCC=5V, VOUT=1V, IOUT=0 to 3A)



Time 200µs/div

Load Transient Response (VIN=Vcc=3.3V, Vout=1V, Iout=0 to 3A)



Time 200µs/div



Application Information

1. Overview

The AP3436/A is a 3A synchronous buck (step-down) converter with two integrated N-channel MOSFETs. For AP3436, the regulator operates in PWM mode with 1.25MHz switching frequency internally, regardless of if the load current is high or low. For AP3436A, when the load is very light, the regulator automatically operates in the PSM mode to minimize the switching loss, thus achieving high efficiency at light load. When the load increases, the regulator automatically switches over to a current-mode PWM operating at nominal 1.25MHz switching frequency.

2. Power On Reset

A Power On Reset (POR) circuitry continuously monitors the supply voltage at VCC pin. Once the rising POR threshold is exceeded, the AP3436/A sets itself to active state and is ready to accept chip enable command. The rising POR threshold is typically 2.75V.

3. Soft Start

A built-in soft-start is used to prevent surge current from power supply input V_{IN} during turn on (Referring to the Functional Block Diagram). The error amplifier is a three-input device. Reference voltage V_{REF} or the internal soft-start voltage Vss whichever is smaller dominates the behavior of the non-inverting inputs of the error amplifier. Vss internally ramps up to 0.6V after the soft-start cycle is initiated. The ramp is created digitally, so the output voltage will follow the Vss signal and ramps up smoothly to its target level.

4. EN Function

The AP3436/A provides Enable Function. Pulling this pin higher than 1.6V statically enables the AP3436/A while pulling the pin lower than 0.8V statically for longer than $10\mu s$ will shutdown the IC.

5. Adjusting Output Voltage

The output voltage is set with a resistor divider from the FB pin. It is recommended to use divider resistors with 1% tolerance or better. Start with a $100k\Omega$ for the resistor R1 and use the following equation to calculate R2. Consider using larger value resistors to improve efficiency at very light loads. If the values are too high, the regulator is more susceptible to noise and the voltage errors caused by FB input current are noticeable.

$$R2 = \frac{R1 \times 0.6}{V_{OUT} - 0.6}$$

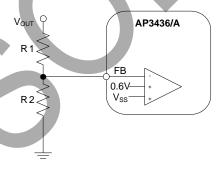


Figure 1. Voltage Divider Circuit

6. Short Circuit Protection (SCP)

The AP3436/A has Over Current Protection (OCP) and Under Voltage Protection (UVP) functions.

6.1 OCP Function

The high side switch current is detected during each cycle. During SCP conditions, the output voltage is pulled down and the switch current is increased. Once the increased high side switching current is detected to trigger the current limit of high side switch, the high side switch will be immediately turned off and will not be turned on again until the next switching cycle. When over current condition is removed, the AP3436/A will recover back to normal operation again.

6.2 UVP Function

The FB voltage is also monitored for Under Voltage Protection. The UV threshold is set at 0.2V. The under voltage protection has 65µs triggered delay. When UVP is triggered, both high side and low side are shutdown immediately. The UVP is a latched function, reset power supply or EN pin to restart AP3436/A again.



Application Information (Cont.)

7. Over Voltage Protection (OVP)

The output voltage is continuously monitored for Over Voltage Protection by FB pin. When it is larger than 1.67 times as setting, the OVP function is triggered. The Over Voltage Protection has 65µs triggered delay.

When OVP is triggered, both high side and low side are shutdown immediately and the output voltage is discharged by an internal $1k\Omega$ resistor.

8. Power Good

The PGOOD pin output connects an open drain MOSFET. The output is pulled low when the FB voltage enters the fault condition by falling below 75% or rising above 125% of the nominal internal reference voltage. There is a 7% hysteresis on the threshold voltage, so when the FB voltage rises to the good condition above 82% or falls below 118% of the internal voltage reference the PGOOD output MOSFET is turned off. It is recommended to use a pull-up resistor between the values of $3k\Omega$ and $100k\Omega$ to a voltage source that is 5V or less.

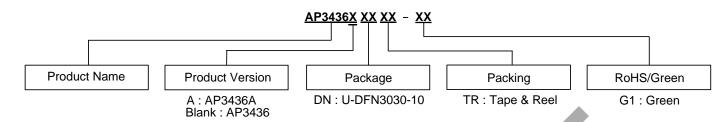
9. Thermal Shutdown

The device implements an internal thermal shutdown to protect itself if the junction temperature exceeds +160°C. Switching is stopped when the junction temperature exceeds the thermal trip threshold. Once the die temperature decreases below +140°C, the device reinitiates the soft start operation. The thermal shutdown hysteresis is +20°C.



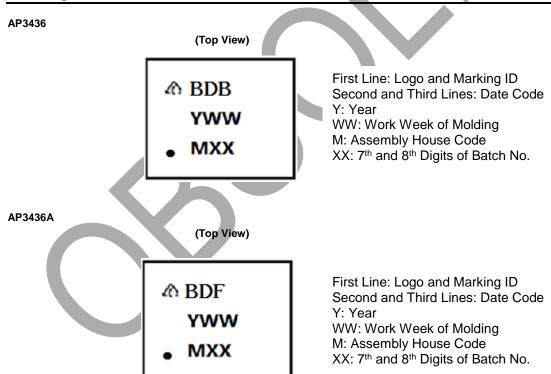


Ordering Information



Package	Package Temperature Function Part Number		Marking ID	Packing	
LL DEN2020 40	40 to 195°C	PWM	AP3436DNTR-G1	BDB	5000/Tape & Reel
U-DFN3030-10	-40 to +85°C	PWM/PSM	AP3436ADNTR-G1	BDF	5000/Tape & Reel

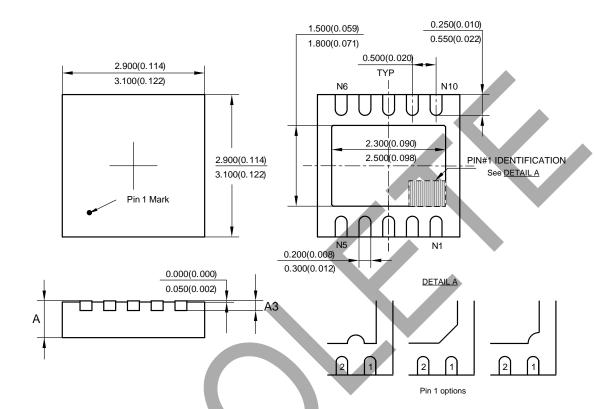
Marking Information





Package Outline Dimensions (All dimensions in mm(inch).)

(1) Package Type: U-DFN3030-10

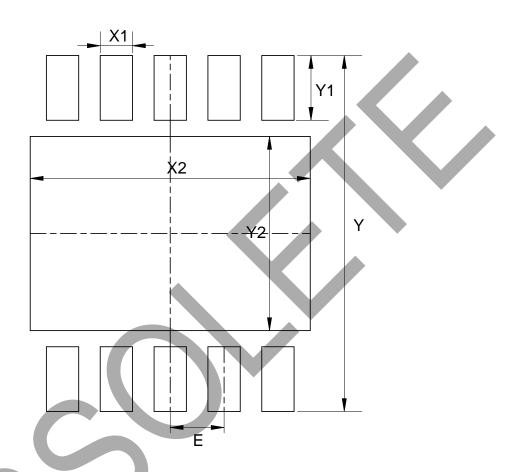


	Symbol		,	A		A3			
1	Syllibol	min(mm)	max(mm)	min(inch)	max(inch)	min(mm)	max(mm)	min (inch)	max(inch)
	Option 1	0.700	0.800	0.028	0.031	0.153	0.253	0.006	0.010
	Option 2	0.570	0.630	0.022	0.025	0.150 (Typ)		0.006	(Тур)



Suggested Pad Layout

(1) Package Type: U-DFN3030-10



Dimensions	Y	X1	Y1	X2	Y2	E
Diffictions	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	3.300/0.130	0.300/0.012	0.600/0.024	2.600/0.102	1.800/0.071	0.500/0.020



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